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Docket No. 740819-617

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

n re REISSUE Application of)	3/105
U.S. Patent No. 6,117,700)	1270
Applicant: Kenji ORITA et al.) Box Reissue	
ssued: September 12, 2000)	
For: METHOD FOR FABRICATING)	
SEMICONDUCTOR DEVICE)	
HAVING GROUP III NITRIDE)	

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents Washington, D.C. 20231

Sir:

In accordance with the duty of disclosure as set forth in 37 C.F.R. §1.56, Applicants hereby submit the following information in conformance with 37 C.F.R. §§ 1.97 and 1.98. Pursuant to 37 C.F.R. § 1.98, a copy of each of the documents cited is enclosed.

Japanese Patent Publication Gazette No. 6-9258 was laid open to the public inspection in Japanese Patent Application Laid Open Gazette No. 2-257679 and an English abstract of No. 2-257679 is enclosed.

A discussion of Japanese Patent Publication for Opposition No. 6-9258 and Japanese Laid-Open Publication Nos. 8-213656, 6-275868, 10-163529, and 10-144960 is given in the specification at column 1, line 62 to column 2, line 61.

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It is requested that the accompanying information disclosure statement be considered and made of record in the above-captioned application. To assist the Examiner, the documents are listed on the attached form PTO-1449. It is respectfully requested that an Examiner initialed copy of this form be returned to the undersigned.

Respectfully submitted,

Eric J. Robinson

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